

SK30GD128



SEMITOP® 3

IGBT Module

SK30GD128

Preliminary Data

Features

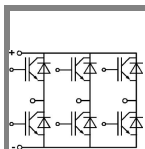
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- High short circuit capability
- SPT = Soft-Punch-Through technology
- $V_{CE,sat}$ with positive coefficient

Typical Applications*

- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS

Remarks

- V_F = chip level value

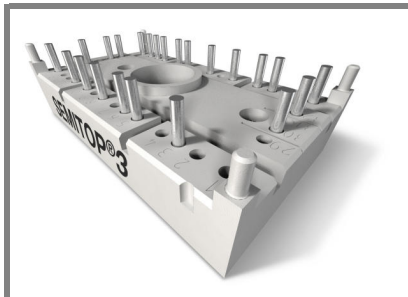


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Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT			
V_{CES}	$T_j = 25^\circ\text{C}$	1200	V
I_C	$T_j = 125^\circ\text{C}$	$T_s = 25^\circ\text{C}$	35 A
		$T_s = 80^\circ\text{C}$	25 A
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$	50	A
V_{GES}		± 20	V
t_{psc}	$V_{CC} = 600\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125^\circ\text{C}$ $V_{CES} < 1200\text{ V}$	10	μs
Inverse Diode			
I_F	$T_j = 150^\circ\text{C}$	$T_s = 25^\circ\text{C}$	37 A
		$T_s = 80^\circ\text{C}$	25 A
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$		A
I_{FSM}	$t_p = 10\text{ ms}; \text{half sine wave } T_j = 150^\circ\text{C}$	180	A
Module			
$I_{t(RMS)}$			A
T_{vj}		-40 ... +150	$^\circ\text{C}$
T_{stg}		-40 ... +125	$^\circ\text{C}$
V_{isol}	AC, 1 min.	2500	V

Characteristics		$T_s = 25^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 1\text{ mA}$	4,5	5,5	6,5	V
I_{CES}	$V_{GE} = 0\text{ V}, V_{CE} = V_{CES}$	$T_j = 25^\circ\text{C}$		0,1	mA
		$T_j = 125^\circ\text{C}$		0,1	mA
I_{GES}	$V_{CE} = 0\text{ V}, V_{GE} = 20\text{ V}$			200	nA
V_{CE0}		$T_j = 25^\circ\text{C}$	1,15		V
		$T_j = 125^\circ\text{C}$	1		V
r_{CE}	$V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}$	24		$\text{m}\Omega$
		$T_j = 125^\circ\text{C}$	44		$\text{m}\Omega$
$V_{CE(sat)}$	$I_{Cnom} = 25\text{ A}, V_{GE} = 15\text{ V}$	$T_j = 25^\circ\text{C}_{chiplev.}$	1,9		V
		$T_j = 125^\circ\text{C}_{chiplev.}$	2,1		V
C_{ies}	$V_{CE} = 25, V_{GE} = 0\text{ V}$	$f = 1\text{ MHz}$	1,9		nF
C_{oes}			0,16		nF
C_{res}			0,09		nF
Q_G	$V_{GE} = 0 \dots 20\text{ V}$		296		nC
$t_{d(on)}$	$R_{Gon} = 15\ \Omega$	$V_{CC} = 600\text{ V}$ $I_C = 30\text{ A}$	55		ns
t_r			26		ns
E_{on}			2,8		mJ
$t_{d(off)}$	$R_{Goff} = 15\ \Omega$	$T_j = 125^\circ\text{C}$ $V_{GE} = \pm 15\text{ V}$	284		ns
t_f			40		ns
E_{off}			2,19		mJ
$R_{th(j-s)}$	per IGBT			1	K/W

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Remarks

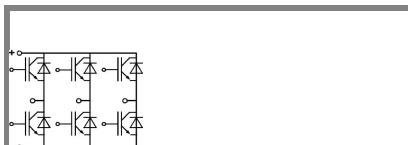
- V_F = chip level value

Characteristics

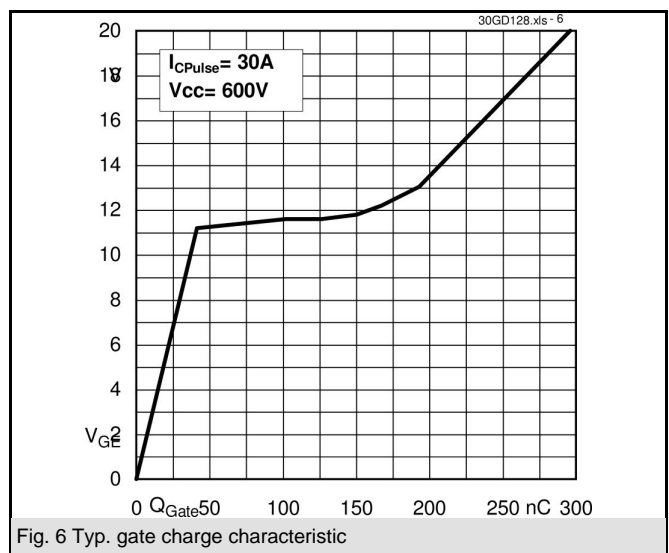
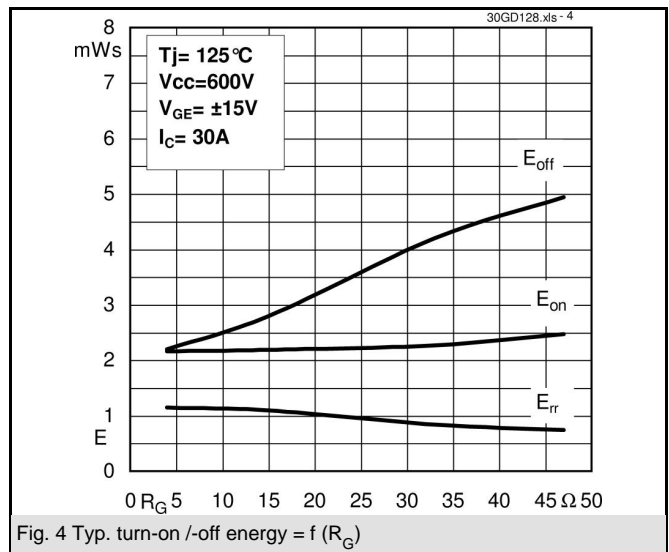
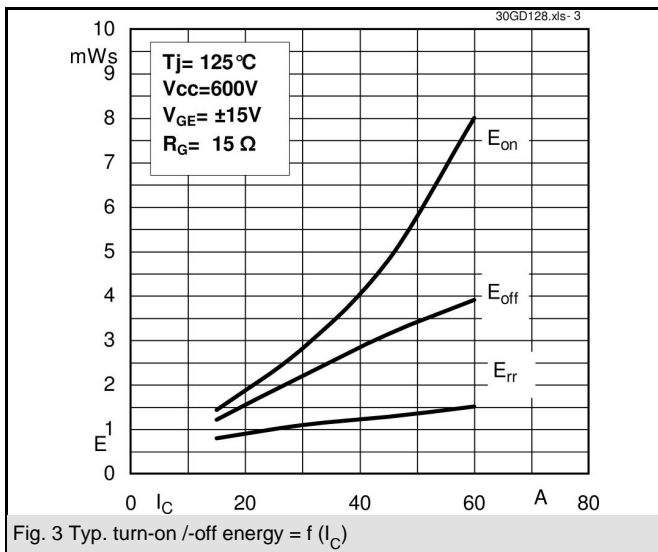
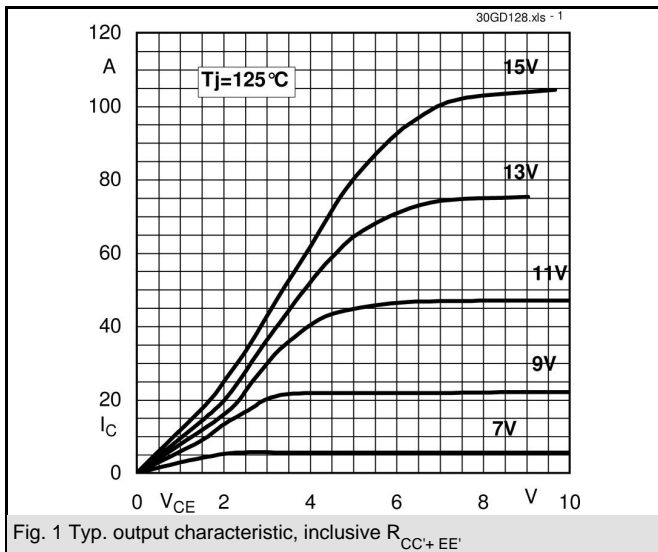
Symbol	Conditions	min.	typ.	max.	Units
Inverse Diode					
$V_F = V_{EC}$	$I_{Fnom} = 25 \text{ A}; V_{GE} = 0 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}_{chiplev.}$	2		V
		$T_j = 125 \text{ }^\circ\text{C}_{chiplev.}$	1,8		V
V_{F0}			1	1,2	V
r_F			32	44	m Ω
I_{RRM}	$I_F = 22 \text{ A}$		25		A
Q_{rr}	$di/dt = -500 \text{ A}/\mu\text{s}$		4,5		μC
E_{rr}	$V_{CC} = 600\text{V}$		1		mJ
$R_{th(j-s)D}$	per diode			1,2	K/W
M_s	to heat sink M1			2	Nm
w			19		g

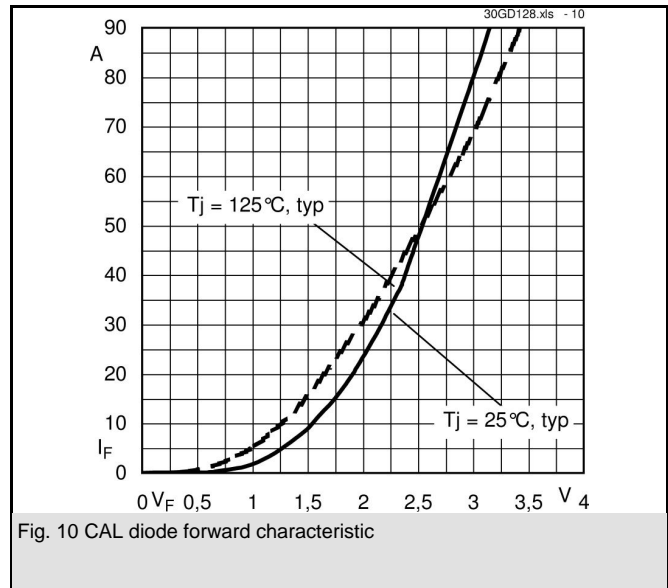
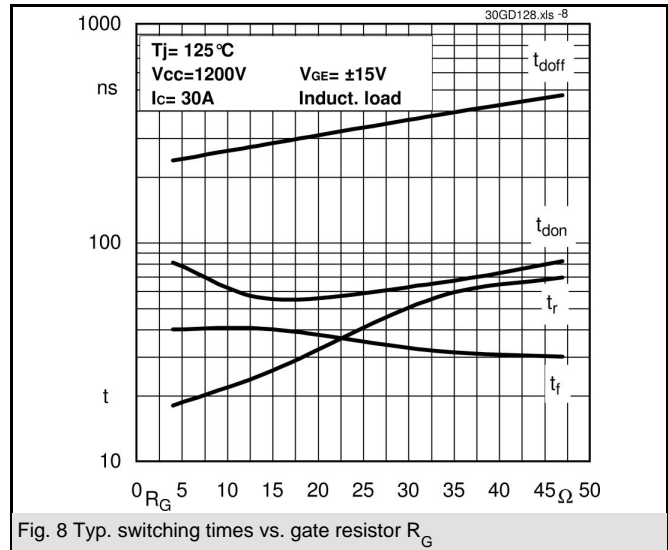
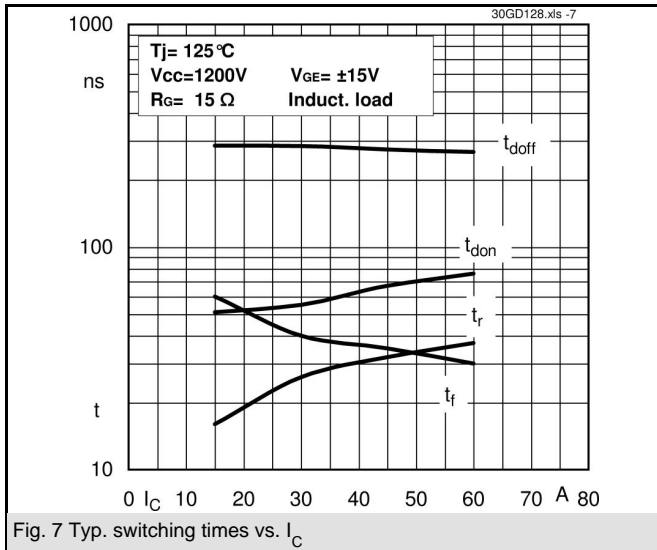
This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

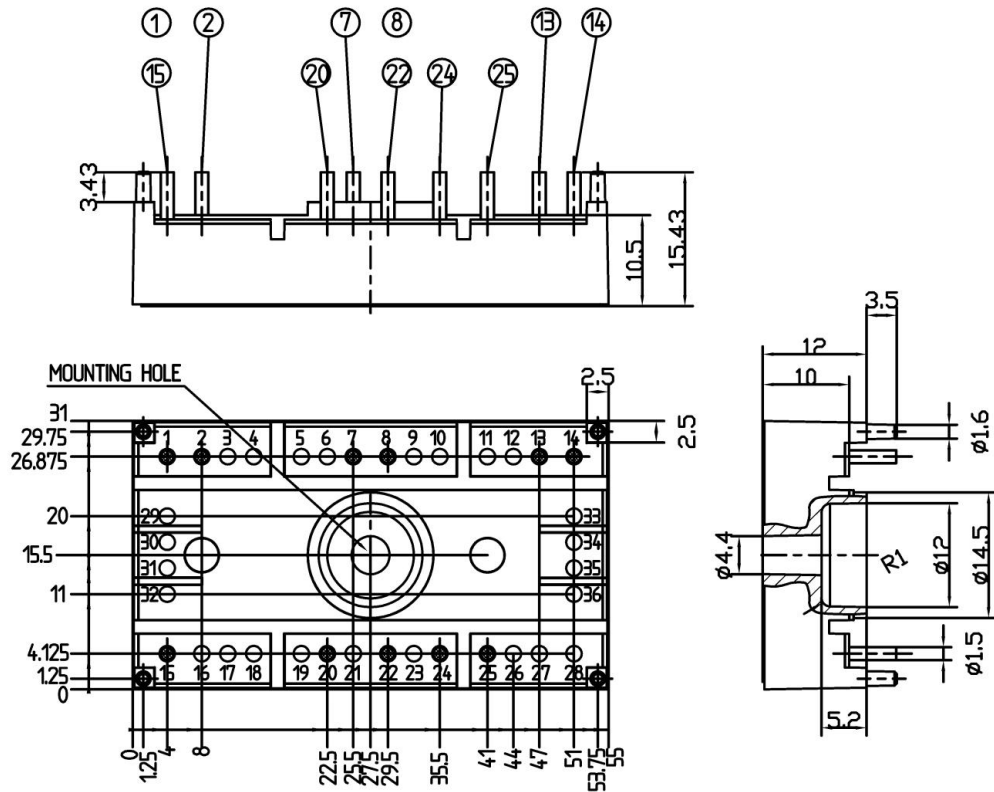
* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.



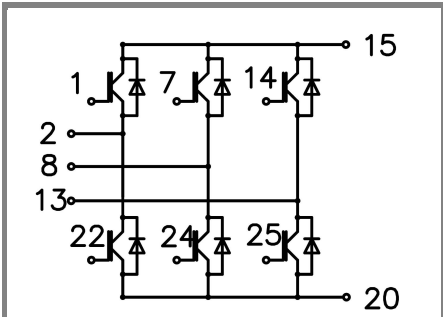
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Case T12 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T12

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